NSN 5962-01-411-6183

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Features Provided:

Electrostatic sensitive and burn in and hermetically sealed and monolithic

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

4.5 volts power source and 5.5 volts power source

Memory Device Type:

First-in first-out

Hybrid Technology Type:

Monolithic

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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